



SMD Temperature Compensated Crystal Oscillator

SMD TCXO using analogue ASIC for compensation and an optional Enable/Disable pin for efficient power management.

Product description

The I(V)T2200J employs an analogue ASIC for the oscillator and a high order temperature compensation circuit in a 2.5×2.0 mm size package. The device can be placed in power down mode through a single input pin. During standard operation, power consumption is minimized by operating down to a supply voltage of 1.8V. The I(V)T2200J's high stability, low power consumption, small footprint and powerful compensation method makes it a TCXO ideally suited for demanding GPS mobile applications.



±1 max

ppm

Applications

- Consumer
- Communications
- GPS
- · Feature phone

Features

• Excellent phase noise performance

SPECIFICATION REFERENCES

• Frequency slope and perturbation specifications can be customized to the application requirement

Description

• Standard temperature stability choices are ±0.5ppm, ±1ppm, ±1.5ppm and ±2.5ppm over wide temperature ranges

Specifications

Parameter

1.0 Line

2.10

Long term stability

1.1 1.2 1.3 1.4	Model description RoHS compliant Reference number Rakon part number	IT2200J / IVT2200J / IT2200JP Yes		
2.0	FREQUENCY CHARACTERISTICS			
Line	Parameter	Test Condition	Value	Unit
2.1	Frequency		10 to 52	MHz
2.2	Frequency calibration	Offset from nominal frequency measured at 25°C±2°C	±1 max	ppm
2.3	Reflow shift	Two consecutive reflows as per attached profile after 1 hour recovery at 25°C	±1 max	ppm
2.4	Temperature range	The operating temperature range over which the frequency stability is measured	-40 to 85	°C
2.5	Frequency stability over temperature	Referenced to the midpoint between minimum and maximum frequency value over the specified temperature range. Control voltage set to midpont of control voltage (Note 1)	±0.5 to 2.5	ppm
2.6	Frequency slope	Minimum of 1 frequency reading every 2°C over the operating temperature range (Note 1) $$	0.1 to 1	ppm/°C
2.7	Static temperature hysteresis	Frequency change after reciprocal temperature ramped over the operating range. Frequency measured before and after at 25°C	0.6 max	ppm
2.8	Sensitivity to supply voltage variations	Supply voltage varied ±5% at 25°C	±0.2 max	ppm
2.9	Sensitivity to load variations	±10% load change at 25°C (Note 2)	±0.2 max	ppm

Frequency drift over 1 year at 25°C

3.0	POWER SUPPLY			
Line	Parameter	Test Condition	Value	Unit
3.1	Supply voltage	Nominal supply voltage range	1.8 to 3.3	V
3.2	Current	At maximum supply voltage (Note 2)	2 max	mA
4.0	CONTROL VOLTAGE (VC	20)		
Line	Parameter	Test Condition	Value	Unit
4.1	Control voltage range	The nominal control voltage value is midway between the minimum and maximum. Voltage control should not exceed the supply voltage +0.2 V or GND. Supply voltage ≤2.3 V	0.3 to 1.5	V
4.2	Control voltage range	The nominal control voltage value is midway between the minimum and maximum. Voltage control should not exceed the supply voltage +0.2 V or GND. Supply voltage >2.3 V	0.4 to 2.4	V
4.3	Frequency tuning	Frequency shift from minimum to maximum control voltages	±10 min	ppm
4.4	Port input impedance	Measured between Control voltage and GND pin	500	kΩ
5.0	OSCILLATOR OUTPUT			
Line	Parameter	Test Condition	Value	Unit
5.1	Output waveform	DC coupled clipped sine-wave (Note 3)		
5.2	Output voltage level	At minimum supply voltage (Note 2)	0.8 min	V
5.3	Output load resistance	Refer to test circuit. Typical load $10k\Omega$	9 to 11	kΩ
5.4	Output load capacitance	Refer to test circuit. Typical load 10pF	9 to 11	pF
5.5	Start up time (amplitude)	Within 90% of specified output level	0.5 max	ms
5.6	Start up time (frequency)	Within ±0.5ppm of steady state frequency	2 max	ms
6.0	POWER DOWN MODE (E	Enable/Disable Pin)		
Line	Parameter	Test Condition	Value	Unit
6.1	Power down	RF, Disabled (Minimum GND)	20 max	%Vcc
6.2	Normal operating mode	RF, Enabled (Maximum Vcc)	80 min	%Vcc
6.3	Stand-by current	Typical value <0.01μA	1 max	μA
6.4	Start up time (amplitude)	Within 90% of specified output level	0.5 max	ms
6.5	Start up time (frequency)	Within ±0.5ppm of steady state frequency	2 max	ms
7.0	CCD DUACE NOTCE			
7.0 Line	SSB PHASE NOISE Parameter	Test Condition	Value	Unit
7.1	SSB phase noise power density at 1Hz	Typical value for a 38.4 MHz oscillator at 25°C	-62	dBc/Hz
7.2	offset SSB phase noise power density at 10Hz offset	Typical value for a 38.4 MHz oscillator at 25°C	-86	dBc/Hz
7.3	SSB phase noise power density at 100Hz offset	Typical value for a 38.4 MHz oscillator at 25°C	-109	dBc/Hz
7.4	SSB phase noise power density at 1kHz offset	Typical value for a 38.4 MHz oscillator at 25°C	-132	dBc/Hz
7.5	SSB phase noise power density at 10kHz offset	Typical value for a 38.4 MHz oscillator at 25°C	-148	dBc/Hz

8.0	ENVIRONMENTAL	
Line	Parameter	Description
8.1	Shock	Half sine-wave acceleration of 3000g peak amplitude. Duration: 0.3ms, Velocity: 12.3ft/s [MIL-STD-202 M213] (Note 4)
8.2	Moisture resistance	1000 hours at 85°C, 85% relative humidity. Biased. [MIL-STD-202 M106g] (Note 4)
8.3	Thermal cycling	1000 temperature cycles, where each cycle consists of a 25 minutes soak time at -40°C followed by a 25 minute soak time at 85°C, with a 60 second maximum transition time between temperatures. Air to air transition. [JESD22 METHOD JA-104C] (Note 4)
8.4	Vibration	10g peak acceleration for 20 minutes. 12 cycles in each of 3 orientations. Test from 10-2000Hz [JESD22-B103-B] (Note 4)
8.5	Storage temperature	-40 to 85°C
9.0	MARKING	
Line	Parameter	Description
9.1	Туре	Engraved
9.2	Line 1	[R], [XXXX]* = Frequency in MHz (e.g.: 8J00 = 8MHz, 19J2 = 19.2MHz, 100J = 100MHz)
9.3	Line 2	[o] = Pin 1, [XXX] = Internal code, and [XX] = Date code
9.4	* Frequency code	Frequency marking is only represented by the first three significant digits. For exagmple, on an IT2200J TCXO at 16.368MHz, its frequency code marking will be 16J3
10.0	MANUFACTURING INFOR	RMATION
Line	Parameter	Description
10.1	Reflow	Solder reflow processes as per profile attached.
10.2	Packaging description	Tape and reel. Standard packing quantity is 3000 units per reel
11.0	SPECIFICATION NOTES	
Line	Parameter	Description
11.1	Note 1	Parts should be shielded from drafts causing unexpected thermal gradients. Temperatue changes due to ambient air currents on the oscillator can lead to short term frequency drift
11.2	Note 2	Specified for load stated in the Oscillator Output section at 25°C
11.3	Note 3	AC-Coupled outputs require an external capacitor, ≥ 1nF recommended

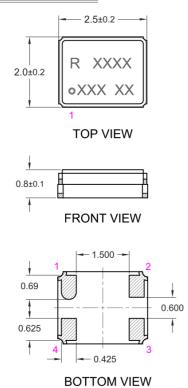
Frequency shift ≤ 1 ppm after environmental conditions

11.4

Note 4

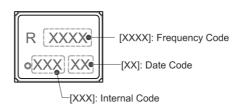
Drawing Name: I(V)T2200J Model Outline

MODEL OUTLINE



LID MARKING *

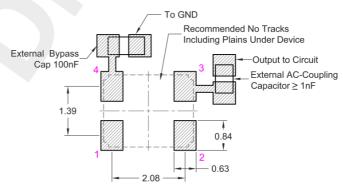
* Marking information is detailed in the specification.



PIN CONNECTIONS

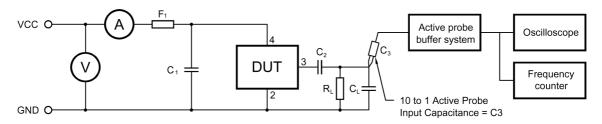
Pin	IT22J	IVT22J	IT22JP	
1	NC / GND	VCO	Enable / Disable**	
2	GND	GND	GND	
3	OUTPUT OUTPUT		OUTPUT	
4	VDD	VDD	VDD	
** Connect to VDD or floating to enable TCXO.				

RECOMMENDED PAD LAYOUT - TOP VIEW

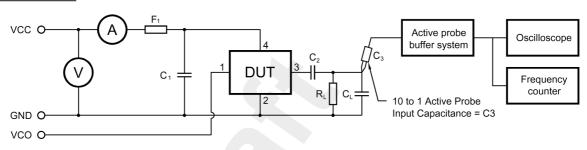


Drawing Name: I(V)T2200J Series Test Circuit

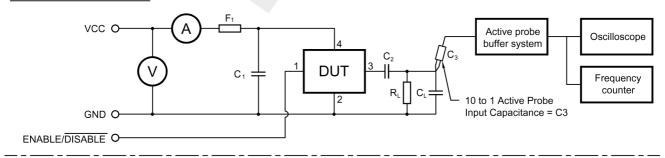
IT22..J TEST CIRCUIT:



IVT22..J TEST CIRCUIT:



IT22..JP TEST CIRCUIT:



 C_1 : 100nF $C_T = C_L + C_3(C_3 - Oscilloscope probe capacitance)$ $C_T = 100$ $C_T = 1$

TITLE: I(V)T2200J SERIES TEST CIRCUIT

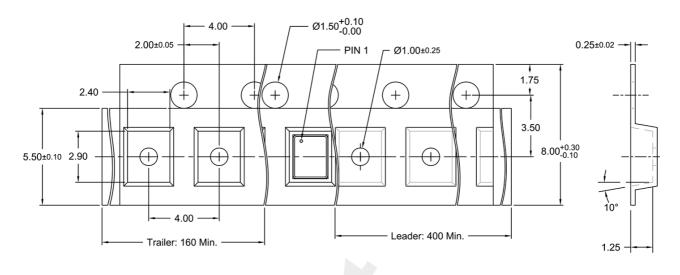
RELATED DRAWINGS:

| REVISION: A | DATE: 15-Mar-12 | SCALE: 1:1 | Millimetres [inch]

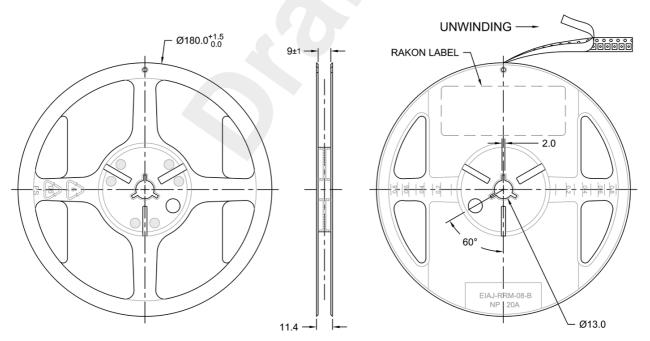


Drawing Name: 2520 Series Tape & Reel

TAPE DETAIL (Scale 5:1)



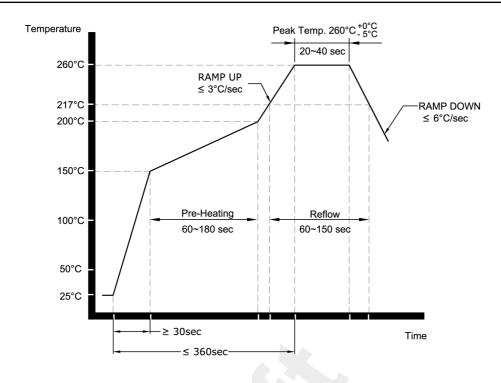
REEL DETAIL (Scale 1: 2.5)



TITLE: 2520 SERIES TAPE & REEL

| RELATED DRAWINGS: | | REVISION: | F | | X.X | = ±0.1 | X.XX | = ±0.05 | X.XX | = ±0.05 | X.XXX | = ±0.05

Drawing Name: Pb-Free Reflow



NOTE:

The product has been tested to withstand the Reflow Profile shown. The Reflow Profile used to solder Rakon products is determined by the solder paste Manufacturer's specification. It is recommended that the Reflow Profile used does not exceed the one shown above.

TITLE: Pb-FREE REFLOW	FILENAME	: CAT541	
RELATED DRAWINGS:	REVISION:	В	
	DATE:	05-Sep-11	rakon
	SCALE:	NTS	
	Millimetres		© 2009 Rakon Limited